

### **General Description**

The SY28902 is a power device (PD) controller with all the features needed to implement the IEEE802.3at/at/bt

protocol. It integrates a multi-state  $\overline{T2P}$  output indicator to indicate the number of classification events received during IEEE 802.3bt-compliant identification and negotiation of available power.

An internal charge-pump is used for enabling the use of external low  $R_{DS(ON)}$  N-channel MOSFETs and increase the end-to-end power transmission efficiency. The SY28902 includes an integrated signature resistor, under-voltage lockout, a power-good output and thermal protection. The start-up inrush current can be adjusted using an external capacitor. Auxiliary power override is supported for voltages higher than 9V applied to the AUX pin.

802.3bt, 802.3at, and 802.3af power levels are all supported by configuring external components.

The SY28902 is available in a 3mm x 3mm MSOP10 package.

### IEEE 802.3bt PD Interface Controller

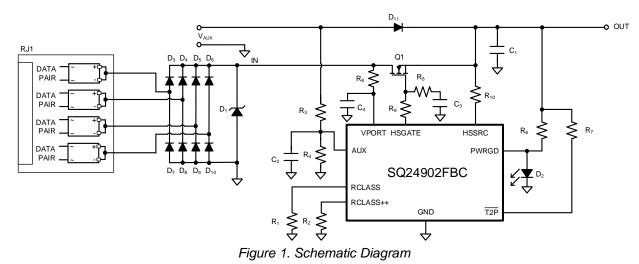
#### Features

- IEEE 802.3af/at/bt Powered Device (PD) Solution for Type 1-4 PoE Applications
- Supports up to 71.3W PDs
- Supports up to 5-Event Classification Sensing
- 100V Robust Surge Protection (Abs. Max.)
- Integrated Signature Resistor
- Thermal Shutdown Protection
- External Hot-swap N-Channel MOSFET for Lowest Power Dissipation and Highest System Efficiency
- Configurable AUX Power Support as Low as 9V
- –40°C to 125°CJunction Temperature Range

### **Applications**

- Security Cameras
- Base Stations
- IEEE 802.3bt Compliant Devices
- Video and VoIP Telephones
- Industrial Applications

### **Typical Application**

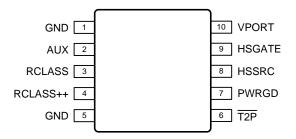




### **Ordering Information**



Pinout (top view)



### **Pinout Description**

Pin Name	NO.	TYPE	Pin Description				
GND	1,5	-	Device ground.				
AUX	2 I		Auxiliary sense pin. Connect a resistive divider from the auxiliary power input to AUX to configure the voltage at which the auxiliary supply takes over. In auxiliary power operation, HSGATE is pulled down, the signature resistor disconnects, classification is disabled, the				
			PWRGD pin is high impedance and $\overline{T2P}$ indicates the maximum available power. Connect to GND when not used.				
RCLASS	3	0	Configurable PoE classification resistor.				
RCLASS++	4	0	Configurable PoE classification resistor.				
T2P	6	0	PSE type indicator: Open-drain output.				
PWRGD	7	0	Power good indicator: Open-drain output. Pulled to GND during $V_{\mbox{\tiny CLASS}}$ and inrush stages.				
HSSRC	8	I	External hot-swap MOSFET source. Connect to the source of the external MOSFET.				
HSGATE	9	0	External hot-swap MOSFET gate control output. Connect to the gate of the external MOSFET.				
VPORT	10	I	PD interface upper power rail and external hot-swap MOSFET drain connection.				



### **Block Diagram**

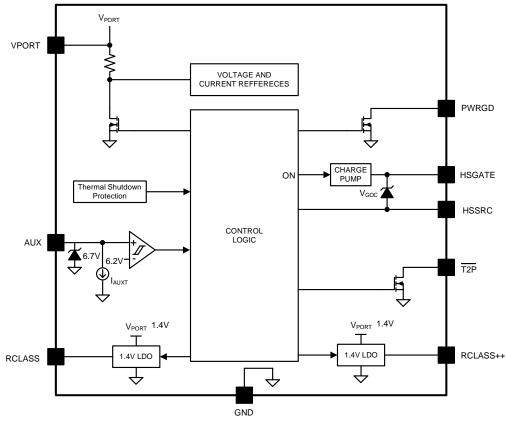


Figure 2. Block Diagram

## **Absolute Maximum Ratings**

Parameter (Note1) (Note4)	Min	Мах	Unit
VPORT, HSSRC, HSGATE, $\overline{T2P}$ , PWRGD	-0.3	100	
HSGATE to HSSRC	V <sub>HSSRC</sub> -0.2	V <sub>HSSRC</sub> +14	V
RCLASS, RCLASS++	-0.3	6 (and ≤ VPORT)	
HSGATE Current	-20	20	
AUX Current	-1.4	1.4	mA
T2P, PWRGD Current		5	
Junction Temperature, Operating	-40	125	
Lead Temperature (Soldering, 10sec.)		300	°C
Storage Temperature	-65	150	

### **Thermal Information**

Parameter (Note2)	Тур	Unit
θ <sub>JA</sub> Junction-to-ambient Thermal Resistance	135.2	°C AM
θ <sub>JC</sub> Junction-to-case Thermal Resistance	25	°C/W
$P_D$ Power Dissipation $T_A=25^{\circ}C$	0.74	W



## **Recommended Operating Conditions**

Parameter (Note5)	Min	Max	Unit
VPORT, HSSRC	0	60	
HSGATE to HSSRC	VHSSRC	V <sub>HSSRC</sub> +14	V
RCLASS, RCLASS++	0	5 (and ≤ VPORT)	
Ambient Temperature	-40	125	С°

### **Electrical Characteristics**

Unless otherwise noted: –40°C≤ TJ ≤125°C. (Note4)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
VPORT Operating Input Voltage		At VPORT pin			60	V
VPORT Signature Range	V <sub>SIG</sub>	At VPORT pin	1.5		10	V
VPORT Classification Range	V <sub>CLASS</sub>	At VPORT pin	12.5		21	V
VPORT Mark Range	Vmark	At VPORT pin, preceded by V <sub>CLASS</sub>	5.6		10	V
VPORT AUX Mode Range		At VPORT pin, AUX > V <sub>AUXT</sub>	8		60	V
Signature/Class Hysteresis Window			1.0			V
Reset Threshold	V <sub>RESET</sub>	At VPORT pin, preceded by V <sub>CLASS</sub>	2.6		5.6	V
Power Good Threshold	Vpg_th		7.1	8	8.9	V
Hot-swap Turn-on Voltage	VHSON			35	37	V
Hot-swap Turn-off Voltage	VHSOFF		30	31		V
Hot-swap On/Off Hysteresis Window			3			V
Supply Current						
Supply Current		V <sub>VPORT</sub> =V <sub>HSSRC</sub> =57V			1	mA
Supply Current During Classification		V <sub>VPORT</sub> = 17.5 V, RCLASS and RCLASS++ open	0.1	0.2	0.5	mA
Supply Current During Mark Event		V <sub>VPORT</sub> =V <sub>MARK</sub> after 1 <sup>st</sup> classification event	0.5		1.8	mA
Detection and Classification Signature				•		
Detection Signature Resistance		V <sub>SIG</sub> (Note 3)	23.7	24.4	25.2	kΩ
Resistance During Mark Event		V <sub>MARK</sub> (Note 3)	5.8	8.3	11	kΩ
RCLASS/RCLASS++ Operating Voltage		$-10mA \ge I_{RCLASS} \ge -36mA, V_{CLASS}$	1.32	1.40	1.43	V
Classification Signature Stability Time		V <sub>VPORT</sub> Step to 17.5V, 34.8Ω from RCLASS or RCLASS++ to GND			2	ms
Analog/Digital Interface				•		
AUX Threshold	V <sub>AUXT</sub>		6	6.2	6.4	V
AUX Hysteresis	V <sub>AUX,HYS</sub>			0.4		V
AUX Pin Hysteresis Current	I <sub>AUXT</sub>	V <sub>AUX</sub> = 6.1V	0.8	2.1	4	μA
T2P Output Low		1mA Load			0.8	V
PWRGD Output Low		1mA Load			0.8	V
PWRGD Leakage Current		V <sub>PWRGD</sub> = 60V			5	μA
T2P Leakage Current		$\overline{T2P} = 60V$			5	μA
Hot-swap Control						
HSGATE Pull-up Current	Igpu	V <sub>HSGATE</sub> - V <sub>HSSRC</sub> = 5V (Note 7)	-27	-22	-18	μA
HSGATE Open Circuit Voltage	V <sub>GOC</sub>	-10µA Load, with Respect to HSSRC	10		17	V



# SY28902

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
HSGATE Pull-down Current		Vhsgate - Vhssrc = 5V	200			μA
Timing	•					
T2P Frequency	fт2P	After PWRGD valid, if IEEE802.3bt PSE is mutually identified	690	840	990	Hz
		After 4-event Classification		50		%
T2P Duty Cycle in PoE Operation (Note 6)		After 5-event Classification (RCLASS++ has resistor to GND) at $T_A = 25^{\circ}$ C.		25		%
T2P Duty Cycle in Auxiliary Supply Operation (Note 6)		$V_{AUX} > V_{AUXT}$ , and RCLASS++ has resistor to GND at $T_A = 25^{\circ}$ C.		25		%

**Note 1:** Stresses beyond the "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Note 2:**  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^{\circ}C$  on the Silergy EVB test board of JEDEC 51-3 thermal measurement standard.

**Note 3:** Signature resistance specifications do not include resistance added by the external diode bridge, which can add as much as 1.1k to the port resistance.

**Note 4:** All voltages with respect to GND unless otherwise noted. Positive currents are into pins; negative currents are out of pins unless otherwise noted.

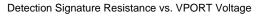
**Note 5:** This IC includes over-temperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed 150°C when over-temperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

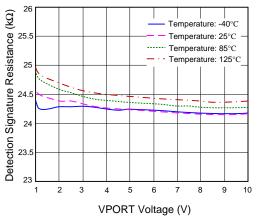
**Note 6:** Specified as the percentage of the period which  $\overline{T2P}$  is low impedance with respect to GND.

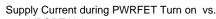
**Note 7:** I<sub>GPU</sub> available in PoE-powered operation. That is, available after  $V_{VPORT} > V_{HSON}$  and  $V_{AUX} < V_{AUXT}$ , over the range where  $V_{VPORT}$  is between  $V_{HSOFF}$  and 60V.

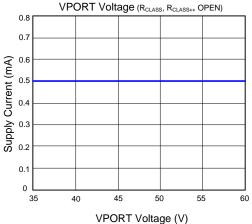


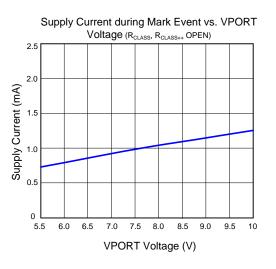
## **Typical Performance Characteristics**

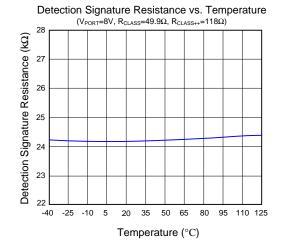




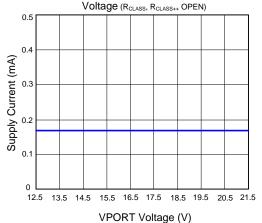


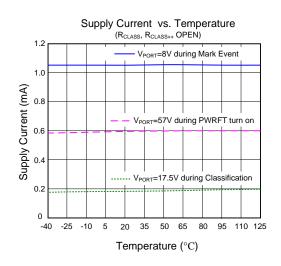




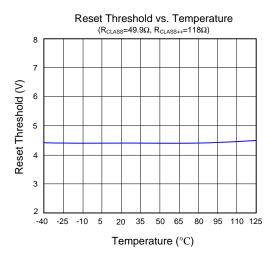


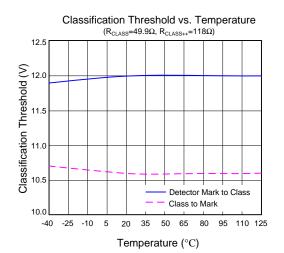
Supply Current during Classification vs. VPORT

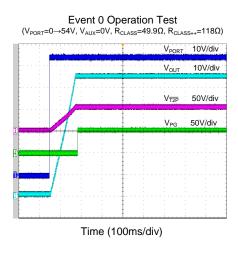


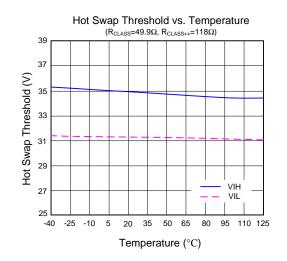




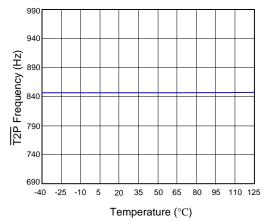


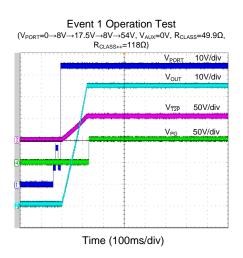






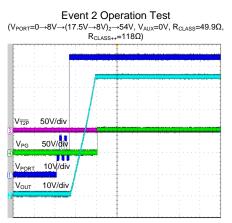
T2P Frequency vs. Temperature



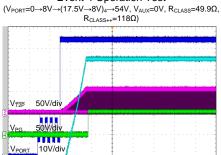




# SY28902



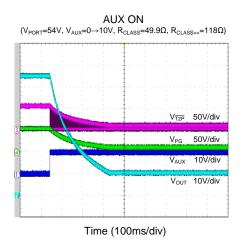
Time (100ms/div)



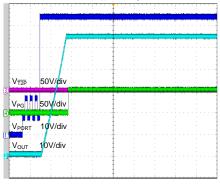
**Event 4 Operation Test** 



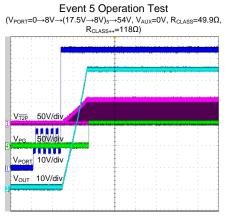
V<sub>OUT</sub> 10V/di



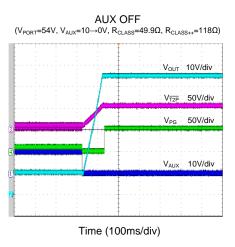
**Event 3 Operation Test**  $\begin{array}{c} (V_{\text{PORT}}=0\rightarrow8V\rightarrow(17.5V\rightarrow8V)_{3}\rightarrow54V,\ V_{\text{AUX}}=0V,\ R_{\text{CLASS}}=49.9\Omega,\\ R_{\text{CLASS}+*}=118\Omega) \end{array}$ 



Time (100ms/div)



Time (100ms/div)





### **Application Information**

### Overview

The IEEE 802.3af/at/bt specification defines a process for safely powering a PD over a cable and removing power if a PD is disconnected. The process proceeds through three operational states: detection, classification, and operation.

The SY28902 is a power device controller containing all the features needed to implement an IEEE802.3at/at/bt protocol.

It integrates the  $\overline{\text{T2P}}$  output indicator to show the number of classification events received during IEEE 802.3bt-compliant mutual identification and negotiation of available power. To eliminate expensive heat sinks, the SY28902 uses external low R<sub>DS(ON)</sub> N-channel hot-swap MOSFET to extend end-to-end power transmission efficiency.

### **Modes of Operation**

#### **Detection Signature**

When a voltage in the range of 2.7V to 10.1V is applied to the PI, a signature resistance of 25 k $\Omega$  signals the Power Supply Equipment (PSE) that the PD is capable of accepting power. Figure 3 shows the detection voltages of the PSE. The PSE calculates the signature resistance using a  $\Delta V/\Delta I$  measurement technique.

The SY28902 integrates a temperature-compensated, precision 24.4k signature resistor between the VPORT and GND pins. The PSE requests power to be applied if a valid PD is recognized. Typically, the SY28902 signature resistor is smaller than 25k to compensate for the additional series resistance on the line.

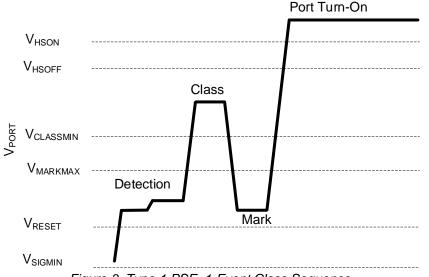


Figure 3. Type 1 PSE, 1-Event Class Sequence

#### IEEE 802.3bt Single-Signature vs. Dual-Signature PDs

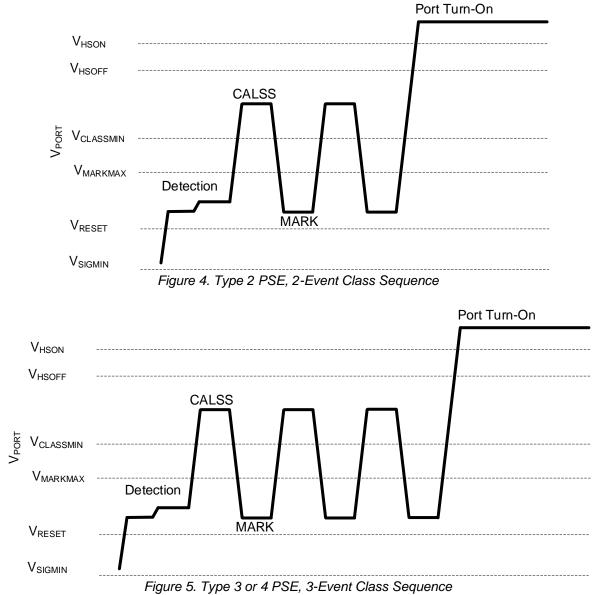
Although PD signature configuration is not defined for Type 1 and Type 2 PDs, a Type 3 or Type 4 PSE may identify such a PD as single-signature or dual-signature. The SY28902 is a single-signature PD that may receive 4-pair power regardless of the PD type, eliminating the additional cost of the second PD controller.

#### **Classification Signature and Mark**

The SY28902 may optionally provide a classification signature to the PSE, indicating the maximum power it will draw during operation. The IEEE specification defines this signature as a constant current draw when the PSE port voltage is in the V<sub>CLASS</sub> range (between 14.5V and 20.5V). If the PSE applies a classification probe voltage, the PSE returns the PD voltage to the mark voltage range before applying another classification probe voltage or powering up the PD.



An example of 1-Event classification is shown in Figure 3. In 2-Event classification, a PSE probes for power classification twice as shown in Figure 4. An IEEE 802.3bt PSE may apply as many as five events before powering up the PD.



#### IEEE 802.3bt Demotion and Physical Classification

IEEE 802.3 PSEs may demote PDs to a lower power state when PD requested power exceeds the PSE available power. IEEE 802.3bt defines physical classification to allow a PD to request a power allocation from the connected PSE and to allow the PSE to inform the PD of the PSE's available power.

As shown in Table 1, the number of class/mark events issued by the PSE directly indicates the power allocated to the PD.

IEEE 802.3bt provides nine PD classes and four PD types as shown in tables 1 and 2. The class of the SY28902 is configured by setting the  $R_{CLS}$  and  $R_{CLS++}$  resistor values.



		E Allocated Cla			NTO		
PD REQUESTED		NUMBER OF PSE CLASS/MARK EVENTS					
CLASS	1	2	3	4	5		
0			1	3W			
1		3.84W					
2		6.49W					
3			1	3W			
4	13W			25.5W			
5	13W	25.5W	1		40W		
6	13W	25.5W	1		51W		
7	13W	25.5W	1	51W	62W		
8	13W	25.5W	1	51W	71.3W		

#### Table 1 DEE Allocated Class Dewar

Note: Bold indicates the PD has been demoted.

#### Table 2. Single-Signature Classification Codes, Power Levels and Resistor Selection

PD REQUESTED	PD POWER		NOMINAL	RESIST	OR(1%)
CLASS	AVAILABLE	PD TYPES	CLASS CURRENT	R <sub>CLS</sub>	R <sub>CLS++</sub>
0	13W	Type 1	2.5mA	1.00kΩ	Open
1	3.84W	Type 1 or 3	10.5mA	140Ω	Open
2	6.49W	Type 1 or 3	18.5mA	76.8Ω	Open
3	13W	Type 1 or 3	28mA	49.9Ω	Open
4	25.5W	Type 2 or 3	40mA	34.8Ω	Open
5	40W	Туре 3	40mA/2.5mA	1.00kΩ	37.4Ω
6	51W	Туре 3	40mA/10.5mA	140Ω	46.4Ω
7	62W	Type 4	40mA/18.5mA	76.8Ω	64.9Ω
8	71.3W	Type 4	40mA/28mA	49.9Ω	118Ω

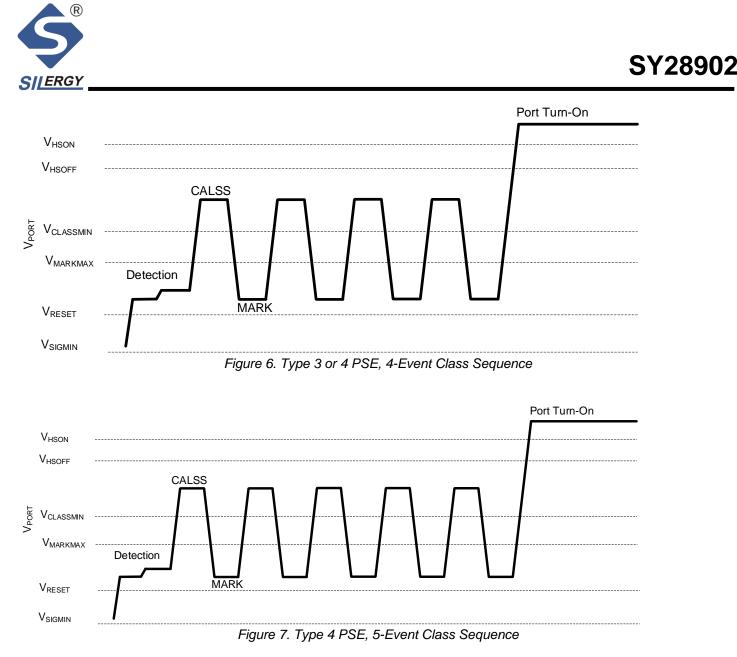
IEEE 802.3bt PSEs present 1-Event classification as shown in Figure 3 to Class 0 through 3 PDs. The PSE receives the class signature of a class 0-3 PD and then powers on if sufficient power is available. Power-limited IEEE 802.3bt PSEs may present 1-Event to Class 4 and higher PDs to demote those PDs to Class 3 (13W).

IEEE 802.3bt PSEs present up to 3-Events classification, according to PSE Type, to Class 4 PDs, as shown in Figure 5. Class 4 PDs present a class signature of 4 on all events. The third event distinguishes a Class 4 PD from a higher-class PD. Power-limited IEEE 802.3bt PSEs may issue 3-Events to Class 5 and higher PDs to demote those PDs to Class 4 (25.5W).

IEEE 802.3bt PSEs present up to 4-Events classification as shown in Figure 6 to Class 5 and 6 PDs. Class 5 and 6 PDs present a class signature of 4 on the first two events and then a class signature of 0 or 1, respectively, on the remaining events. Power-limited IEEE 802.3bt PSEs may issue 4-Events classification to Class 7 and higher PDs to demote those PDs to Class 6 (51W).

IEEE 802.3bt PSEs present up to 5-Events classification as shown in Figure 7 to Class 7 and 8 PDs. Class 7 and 8 PDs present a class signature of 4 on the first two events and then a class signature of 2 or 3, respectively, on the remaining

events. The SY28902 communicates the PSE allocated power to the PD application via the T2P pin. Refer to the T2P Output section of the datasheet for more details.



#### Selection of Classification Resistors (R<sub>CLS</sub> and R<sub>CLS++</sub>)

Select the value R<sub>CLS</sub> and R<sub>CLS++</sub> resistors to configure the corresponding classification currents according to Table 2 to select the PD power classification. Connect each 1% resistor between the R<sub>CLASS</sub>, R<sub>CLASS++</sub> pins, and GND.

#### **Detection Signature Corrupt During Mark Event**

The SY28902 presents a resistance <  $11k\Omega$  to the port according to the requirements of the IEEE 802.3 specification.

#### Inrush Current and Power On

The PSE turns on the power to the PD once the PSE detects and classifies the PD. The SY28902 begins to source  $I_{GPU}$  out of the HSGATE pin when the port voltage rises above the V<sub>HSON</sub> threshold. This current flows into an external capacitor C<sub>GATE</sub>, shown in Figure 8, which causes the gate of the external MOSFET to rise. The external N-channel MOSFET acts as a source follower and causes the voltage ramp on the output bulk capacitor C<sub>OUT</sub>, thereby determining the inrush current (I<sub>INRUSH</sub>). A typical design target for I<sub>INRUSH</sub> is approximately 100mA. The value for C<sub>GATE</sub> can be calculated using the following equation:

$$I_{INRUSH} = I_{GPU} \frac{C_{OUT}}{C_{GATE}}$$



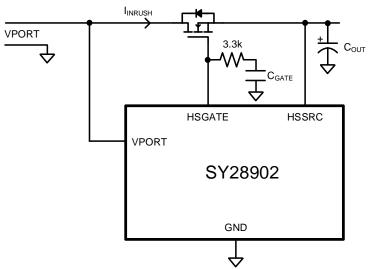


Figure 8. Configuring IINRUSH

The SY28902 internal charge pump enables the use of N-channel MOSETs due to their lower cost and  $R_{DS(ON)}$ . Using a low  $R_{DS(ON)}$  MOSFET maximizes power transmission efficiency, reduces power and heat dissipation, and simplifies thermal design.

#### **Power Good Indicator**

The PWRGD pin can be used for disabling the downstream circuits until the external MOSFET is fully biased and inrush time is complete. The PWRGD pin remains low until HSGATE is charged to approximately 8V above HSSRC. The HSGATE pin remains high, and the PWRGD pin is in high-impedance until the port voltage falls below V<sub>HSOFF</sub>.

#### **Auxiliary Supply Override**

The SY28902 enters auxiliary power supply override mode if the AUX pin is held above  $V_{AUXT}$ . In this mode of operation, the signature resistor disconnects, HSGATE pulls down, classification is turned off, the PWRGD pin is high-impedance, and the T2P pin indicates maximum available power.

The AUX pin allows for setting the auxiliary supply turn on and turn off voltage thresholds,  $V_{AUXON}$ , and  $V_{AUXOFF}$ , respectively. Use the following equations to set  $V_{AUXON}$  and  $V_{AUXOFF}$  using the resistors  $R_1$  and  $R_2$  in (figure 9). Note that an internal 6.7V Zener limits the voltage on the AUX pin.

A capacitor of up to 1000pF may be placed between the AUX pin and the GND to improve noise immunity.  $V_{AUXON}$  must be lower than  $V_{HSOFF}$ .

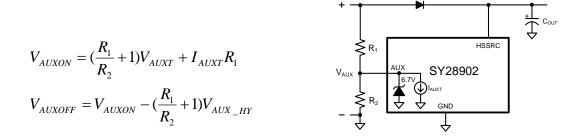


Figure 9. AUX Threshold and Hysteresis Calculation



#### AUX Voltage Limit

If the AUX pin is driven above the internal Zener voltage threshold of 6.7V, the SY28902 will clamp the voltage to this level. For safe operation, the maximum current flowing into the AUX pin has to be lower than 1.4mA. Use a  $R_1$  value higher than the resistance value calculated using the following equation:

$$R_1 \ge \frac{V_{AUX(MAX)} - 6.7V}{1.4mA}$$

#### PD Start Delay

The PD application should not exceed 350 mA within 80ms to meet the requirements of IEEE 802.3 standards when the PSE powers up the port.

#### **T2P** Output Indicator

The  $\overline{T2P}$  pin state is determined by the number of classification events, the RCLASS++ pin, and the AUX pin and also depends on the PSE allocated power. The SY28902 uses a 5-state encoding for the  $\overline{T2P}$  output by changing the pin level and/or the duty cycle. Table 3 lists the  $\overline{T2P}$  state based on the above input conditions:

AUX STATE	PD REQUESTED CLASS(RCLASS/RCLASS++)	NUMBER OF CLASSIFICATION EVENTS	T2P WITH RESPECT TO GND	PSE ALLOCATED POWER
	0-4	NA	Low-Z	AUX Power
AUXILIARY	5-8	NA	25% Low-Z 75% HI-Z	AUX Power
		1	HI-Z	13W
	0-4	≥2	Low-Z	25.5W
		1	HI-Z	13W
PoE		2 or 3	Low-Z	25.5W
	5-8	4	50% Low-Z 50% HI-Z	Min(PD Requested Class, 51W)
	5-0	5	25% Low-Z 75% HI-Z	Min(PD Requested Class, 71.3W)

Table 3. T2P Response based on the PSE Allocated Power, Number of classification events and allocated power

The AUX pin is the highest priority input. When AUX is de-asserted, the device can enter the PoE state, but it exits the PoE state as soon as the auxiliary power is detected. Based on the PD requested class, the  $\overline{T2P}$  pin indicates the highest available power in the auxiliary power state. The auxiliary power supply must be sized to provide at least the level of power required by the PD.

As shown in Table 2, the RCLASS and RCLASS++ pins configure the PD-requested class. The RCLASS++ pin can be used to determine if the PD Class is 0-4 or 5-8.

As shown in Table 1, the amount of power allocated by the PSE is determined by the number of classification events.



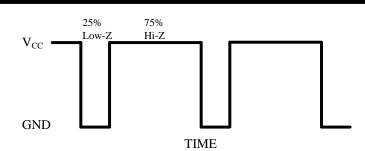


Figure 10. Example of a 25% Low-Z, 75% Hi-Z Response

#### **Thermal Shutdown Protection**

A PD must meet the IEEE 802.3 specification to indefinitely withstand any applied voltage from 0V to 57V.

However, during the classification process, the power dissipation of the SY28902 may be as high as 1.5W. The SY28902 easily tolerates this during the maximum IEEE classification timing but can overheat if this condition persists abnormally. The SY28902 includes a thermal shutdown protection function to protect itself and the downstream equipment under abnormal load conditions. If the junction temperature exceeds the over-temperature threshold, the SY28902 pulls down the HSGATE pin and disables classification.

### **External Interface and Component Selection**

#### **PoE Input Bridge**

A PD needs to perform polarity correction of its input voltage. There are several options for bridge rectifiers: ideal diodes, silicon diodes, and Schottky diodes. When using Schottky or silicon diode bridges, the voltage at the VPORT pin will be reduced due to the forward voltage across the diodes. The SY28902 is designed to tolerate these voltage drops.

Silicon diode bridges perform poorly, are unbalanced from wiring pair to pair, and consume up to 4% of the available power. In addition, thermal runaways can cause significant, non-compliant current unbalance between pair sets. Although using Schottky diodes can help reduce power loss and offer lower forward voltages, Schottky bridges may not be suitable for high-temperature PD applications, due to the increase of leakage currents at high temperature and a dependance of the leakage with voltage, as this can lead to an invalid detection signature.

The increased leakage currents can also back-feed through the unpowered branch and the unused bridge, violating the IEEE 802.3 specifications.

#### Auxiliary Input Diode Bridge

Some PDs require an auxiliary power source to receive AC or DC power. A diode bridge is typically required to handle the polarity correction and voltage rectification.

#### Input Capacitor

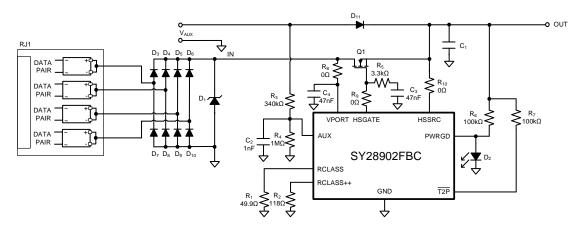
Add a 0.1µF capacitor between VPORT and GND to meet the input impedance requirement of IEEE 802.3 and appropriately bypass the SY28902.

#### Transient Voltage Suppressor

The SY28902 is specified to withstand an absolute maximum input voltage of 100V, and it can tolerate brief over-voltage events due to Ethernet cable surges. To protect the SY28902 from an over-voltage event, a unidirectional transient voltage suppressor (TVS), such as an SMAJ60A, should be used between the VPORT and GND pins.



### **Application Schematic**



#### **BOM List**

Designator Description		Part Number	Manufacturer
C1	/	/	/
C2	1nF/50V, 0603	GRM1885C1H102GA01D	Murata
C <sub>3</sub>	47nF/100V, 0805	GRM21BR72A4473KA01L	Murata
<b>C</b> 4	47nF/100V, 0805	GRM21BR72A4473KA01L	Murata
R1	49.9Ω, 0603	RC0603FR-0749R9L	YAGEO
R <sub>2</sub>	118Ω, 0603	RC0603FR-07118RL	YAGEO
R3	340kΩ, 0603	RC0603FR-07340KL	YAGEO
<b>R</b> 4	1MΩ, 0603	RC0603FR-071ML	YAGEO
R5	3.3kΩ, 0603	RC0603FR-073K3L	YAGEO
R <sub>6</sub>	100kΩ, 0603	RC0603FR-07100KL	YAGEO
R7	100kΩ, 0603	RC0603FR-07100KL	YAGEO
R8, R9,R10	0	/	/
D1	TVS/60V, SMA	SMAJ60A	Littelfuse
D2	LED	/	/
D3-D11	Schottky/100V	SS3100	TOSHIBA
RJ1	RJ45	RJ45-B-1*1	BOOMELE
Q1	NMOS/100V	FDMS86150	Fairchild

#### Layout Considerations

Place resistors  $R_1$  and  $R_2$  close to the SY28902 to avoid excessive parasitic capacitance on the RCLASS and RCLASS++ pins.

Place the transient voltage suppressor (TVS) as close to SY28902 as possible. Place the  $0.1\mu$ F input capacitor with appropriate voltage rating close to the device input pins.



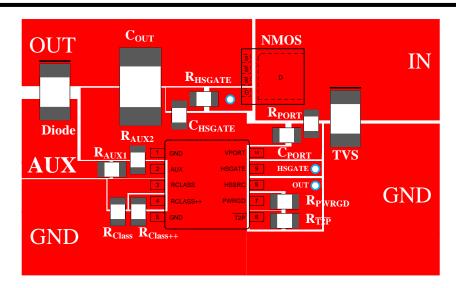
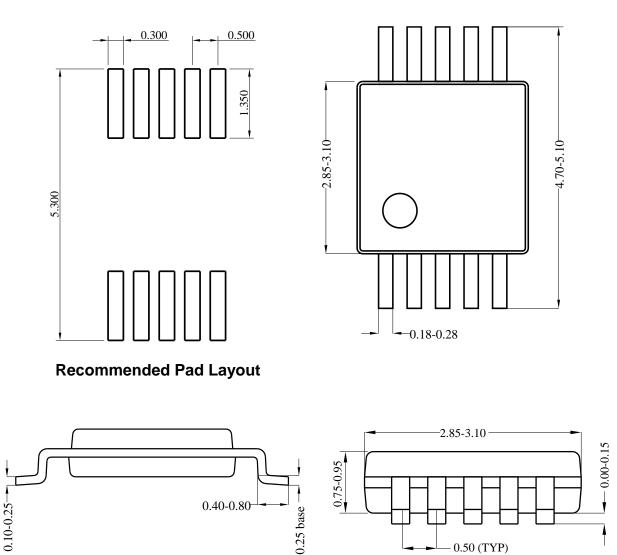


Figure 11. PCB Layout Suggestion





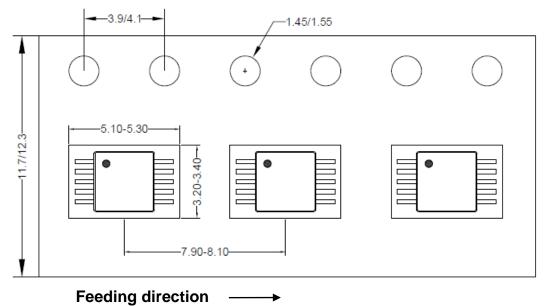


Notes: All dimensions are in millimeters and exclude mold flash and metal burr.

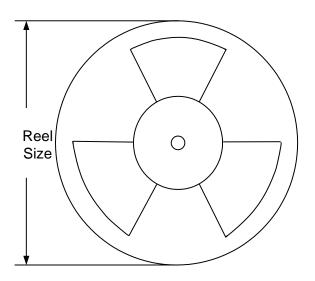


## **Taping & Reel Specification**

## **MSOP10** Taping Orientation



## **Carrier Tape & Reel Specification for Packages**



Package	Tape width	Pocket	Reel size	Trailer	Leader length	Qty per
types	(mm)	pitch(mm)	(Inch)	length(mm)	(mm)	reel
MSOP10	12	8	13"	400	400	



## **Revision History**

Date Revision		Change
Oct.18, 2023	Revision 1.0	Language improvements for clarity.
Jan. 20, 2022	Revision 0.9	Initial Release

The revision history provided is for informational purposes only and is believed to be accurate; however, it is not warranted. Please make sure that you have the latest revision.



#### **IMPORTANT NOTICE**

1. **Right to make changes.** Silergy and its subsidiaries (hereafter Silergy) reserve the right to change any information published in this document, including but not limited to circuitry, specification and/or product design, manufacturing or descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products are sold subject to Silergy's standard terms and conditions of sale.

2. Applications. Application examples that are described herein for any of these products are for illustrative purposes only. Silergy makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Buyers are responsible for the design and operation of their applications and products using Silergy products. Silergy or its subsidiaries assume no liability for any application assistance or designs of customer products. It is customer's sole responsibility to determine whether the Silergy product is suitable and fit for the customer's applications and products planned. To minimize the risks associated with customer's products and applications, customer should provide adequate design and operating safeguards. Customer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Silergy assumes no liability related to any default, damage, costs or problem in the customer's applications or products, or the application or use by customer's third-party buyers. Customer will fully indemnify Silergy, its subsidiaries, and their representatives against any damages arising out of the use of any Silergy components in safety-critical applications. It is also buyers' sole responsibility to warrant and guarantee that any intellectual property rights of a third party are not infringed upon when integrating Silergy products into any application. Silergy assumes no responsibility for any said applications or for any use of any circuitry other than circuitry entirely embodied in a Silergy product.

3. Limited warranty and liability. Information furnished by Silergy in this document is believed to be accurate and reliable. However, Silergy makes no representation or warranty, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. In no event shall Silergy be liable for any indirect, incidental, punitive, special or consequential damages, including but not limited to lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges, whether or not such damages are based on tort or negligence, warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Silergy' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Standard Terms and Conditions of Sale of Silergy.

4. **Suitability for use.** Customer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of Silergy components in its applications, notwithstanding any applications-related information or support that may be provided by Silergy. Silergy products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Silergy product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Silergy assumes no liability for inclusion and/or use of Silergy products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

5. **Terms and conditions of commercial sale**. Silergy products are sold subject to the standard terms and conditions of commercial sale, as published at http://www.silergy.com/stdterms, unless otherwise agreed in a valid written individual agreement specifically agreed to in writing by an authorized officer of Silergy. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Silergy hereby expressly objects to and denies the application of any customer's general terms and conditions with regard to the purchase of Silergy products by the customer.

6. No offer to sell or license. Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights. Silergy makes no representation or warranty that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right. Information published by Silergy regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from Silergy under the patents or other intellectual property of Silergy.

For more information, please visit: www.silergy.com

©2023 Silergy Corp.

All Rights Reserved.